

BCR25FM-12LB

600V - 25A - Triac
Medium Power Use

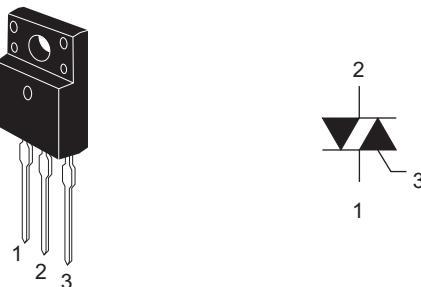
R07DS0964EJ0100
Rev.1.00
Feb 28, 2014

Features

- $I_T(\text{RMS})$: 25 A
- V_{DRM} : 600 V
- T_j : 150 °C
- $I_{\text{FGTI}}, I_{\text{RGTI}}, I_{\text{RGTHI}}$: 50 mA
- Insulated Type
- Planar Passivation Type
- V_{iso} : 2000 V

Outline

RENESAS Package code: PRSS0003AG-A
(Package name: TO-220FP)



1. T_1 Terminal
2. T_2 Terminal
3. Gate Terminal

Applications

Contactless AC switch, electric heater control, light dimmer, on/off and speed control of small induction motor, on/off control of copier lamp

Maximum Ratings

Parameter	Symbol	Voltage class		Unit
		12		
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	600		V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	720		V

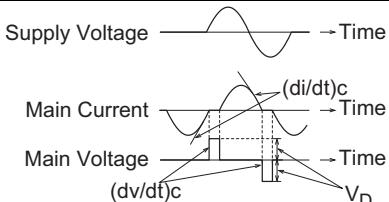
Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_T(\text{RMS})$	25	A	Commercial frequency, sine full wave 360° conduction, $T_c = 62^\circ\text{C}$
Surge on-state current	I_{TSM}	250	A	50 Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusion	I^2t	313	A^2s	Value corresponding to 1 cycle of half wave 50 Hz, surge on-state current
Peak gate power dissipation	P_{GM}	5	W	
Average gate power dissipation	$P_{\text{G(AV)}}$	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I_{GM}	2	A	
Junction Temperature	T_j	-40 to +150	°C	
Storage temperature	T_{stg}	-40 to +150	°C	
Mass	—	1.9	g	Typical value
Isolation voltage ^{Note5}	V_{iso}	2000	V	$T_a = 25^\circ\text{C}$, AC 1 minute, $T_1 \bullet T_2 \bullet G$ terminal to case

Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Repetitive peak off-state current	I_{DRM}	—	—	3.0	mA	$T_j = 125^\circ C, V_{DRM}$ applied
		—	—	5.0	mA	$T_j = 150^\circ C, V_{DRM}$ applied
On-state voltage	V_{TM}	—	—	1.5	V	$T_c = 25^\circ C, I_{TM} = 40 A$, instantaneous measurement
Gate trigger voltage ^{Note2}	I	V_{FGTI}	—	2.0	V	$T_j = 25^\circ C, V_D = 6 V, R_L = 6 \Omega, R_G = 330 \Omega$
	II	V_{RGTI}	—	2.0	V	
	III	$V_{RGTI\text{III}}$	—	2.0	V	
Gate trigger current ^{Note2}	I	I_{FGTI}	—	50	mA	$T_j = 25^\circ C, V_D = 6 V, R_L = 6 \Omega, R_G = 330 \Omega$
	II	I_{RGTI}	—	50	mA	
	III	$I_{RGTI\text{III}}$	—	50	mA	
Gate non-trigger voltage	V_{GD}	0.2	—	—	V	$T_j = 125^\circ C, V_D = 1/2 V_{DRM}$
		0.1	—	—	V	$T_j = 150^\circ C, V_D = 1/2 V_{DRM}$
Thermal resistance	$R_{th(j-c)}$	—	—	2.8	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-state commutation voltage ^{Note4}	$(dv/dt)c$	10	—	—	V/μs	$T_j = 125^\circ C$
		1	—	—	V/μs	$T_j = 150^\circ C$

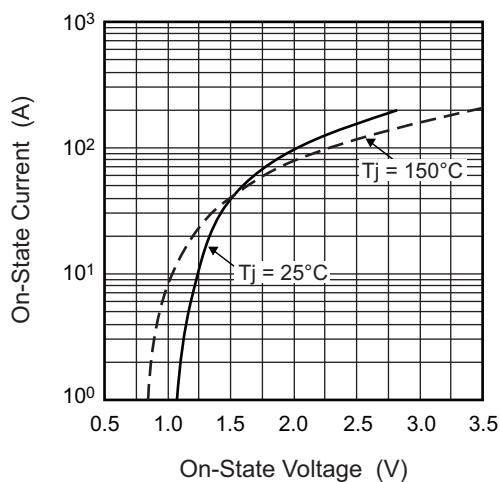
Notes: 1. Gate open.

2. Measurement using the gate trigger characteristics measurement circuit.
3. The contact thermal resistance $R_{th(c-f)}$ in case of greasing is $0.5^\circ C/W$.
4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.
5. Make sure that your finished product containing this device meets your safe isolation requirements.
For safety, it's advisable that heatsink is electrically floating.

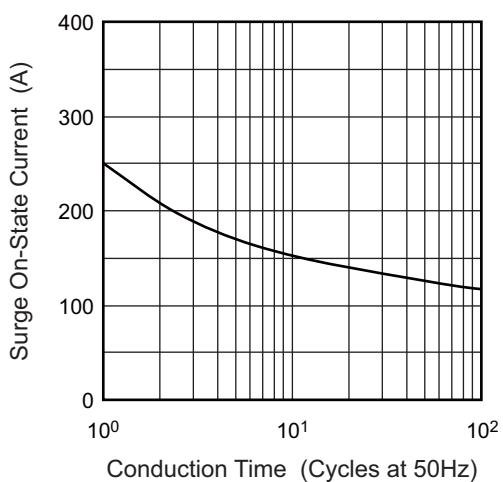
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature $T_j = 125^\circ C/150^\circ C$ 2. Rate of decay of on-state commuting current $(di/dt)c = -13 A/ms$ 3. Peak off-state voltage $V_D = 400 V$	

Performance Curves

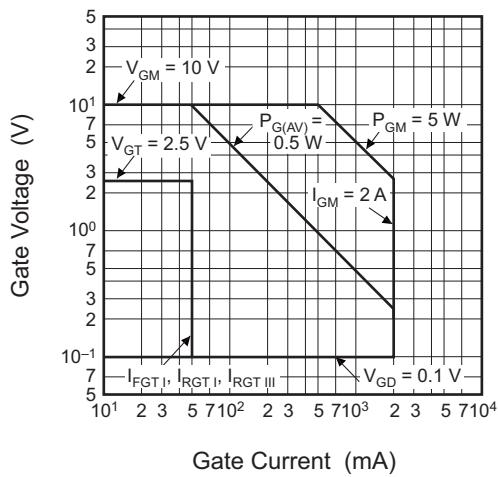
Maximum On-State Characteristics



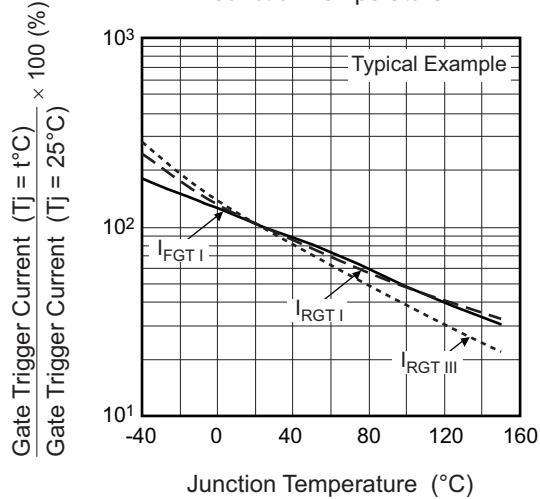
Rated Surge On-State Current



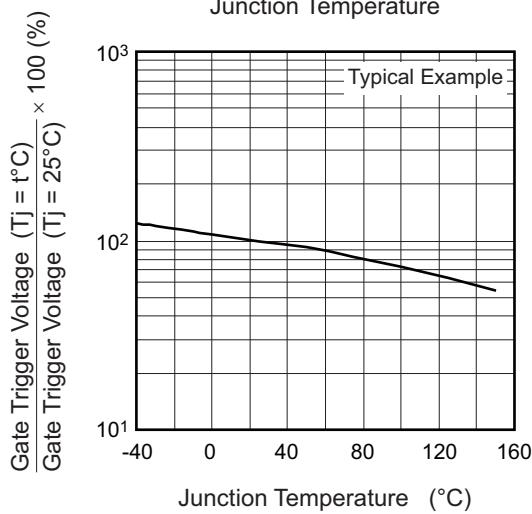
Gate Characteristics (I, II and III)



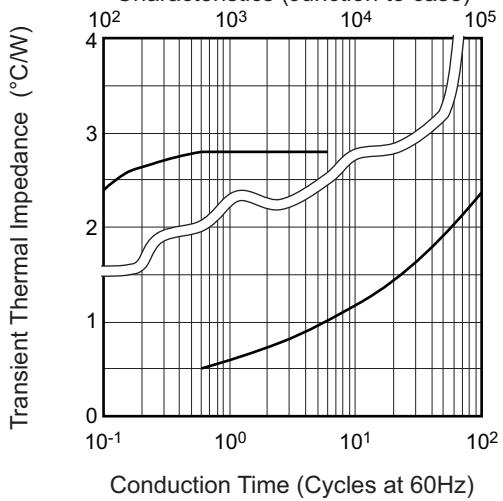
Gate Trigger Current vs. Junction Temperature

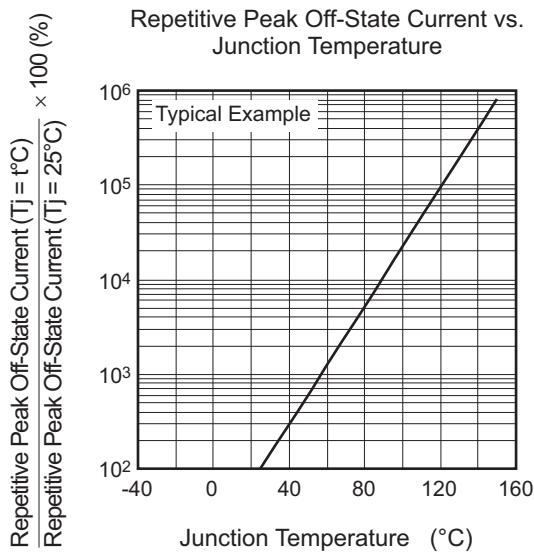
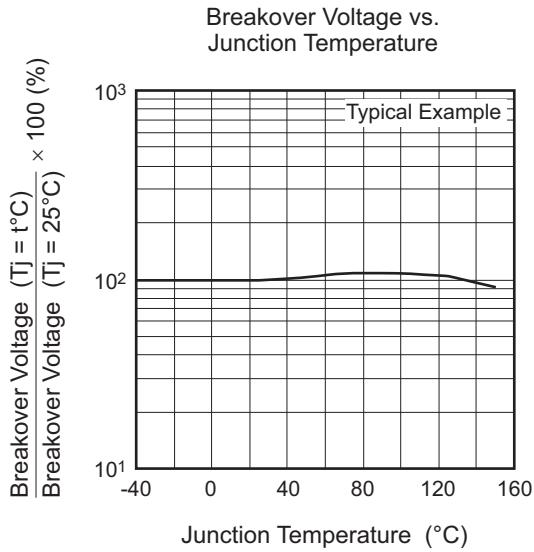
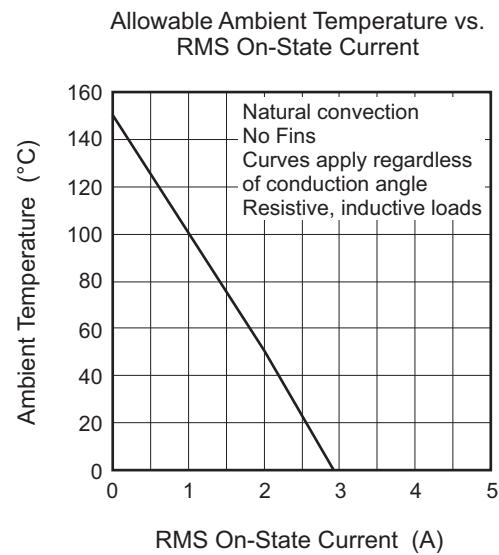
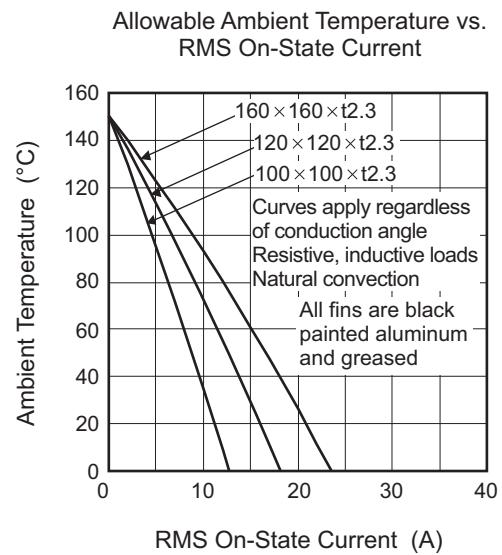
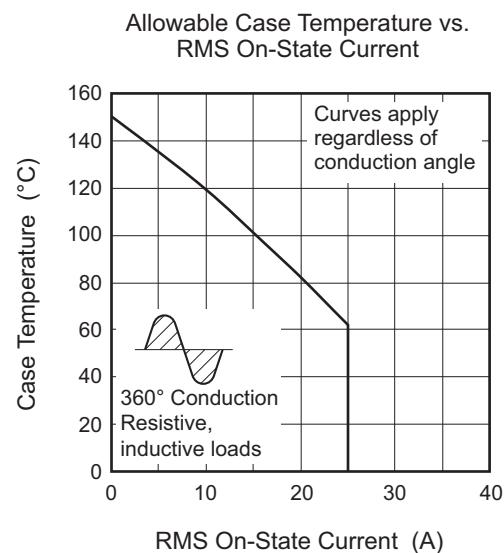
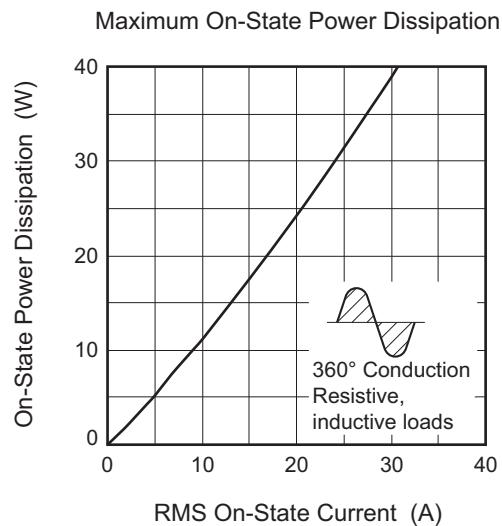


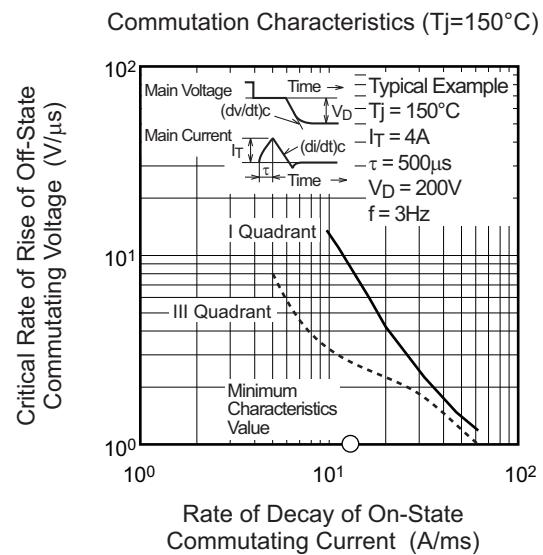
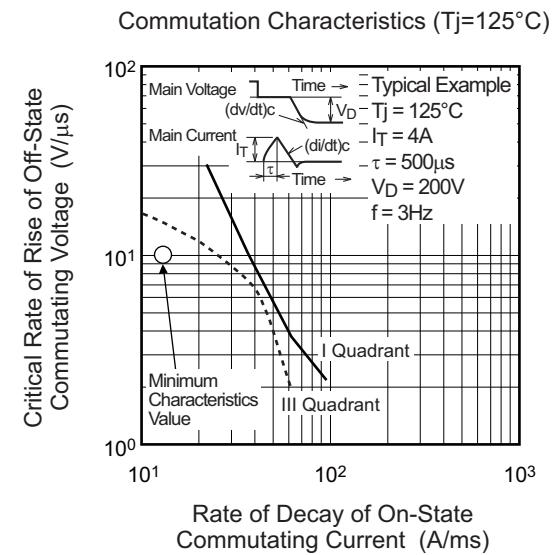
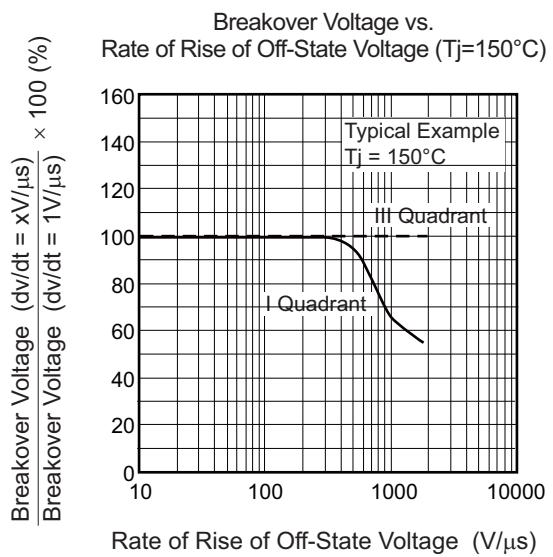
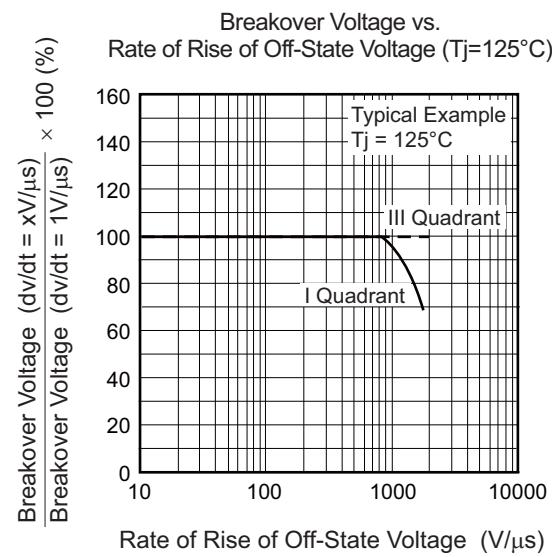
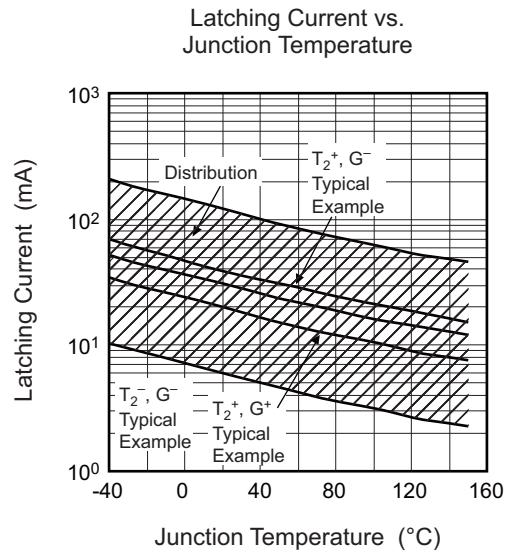
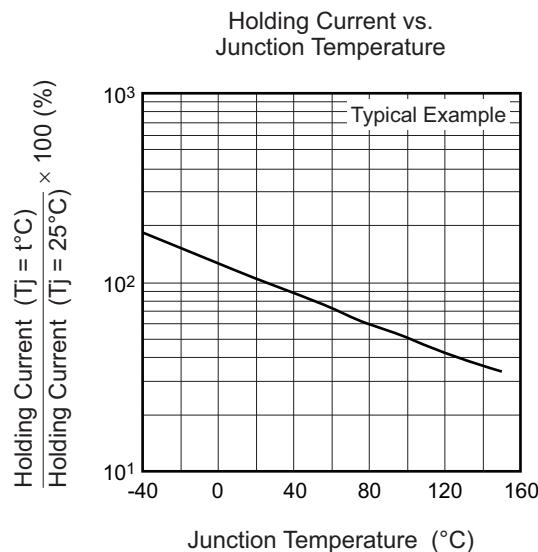
Gate Trigger Voltage vs. Junction Temperature



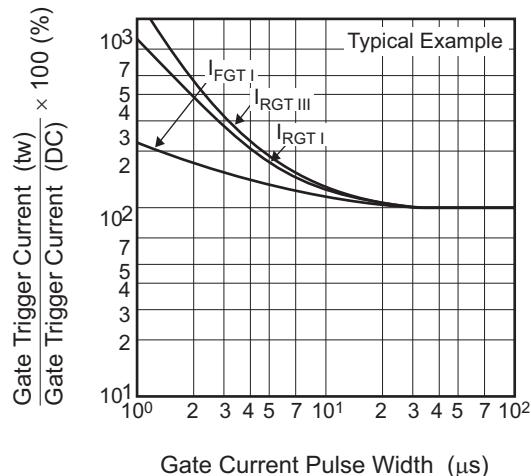
Maximum Transient Thermal Impedance Characteristics (Junction to case)



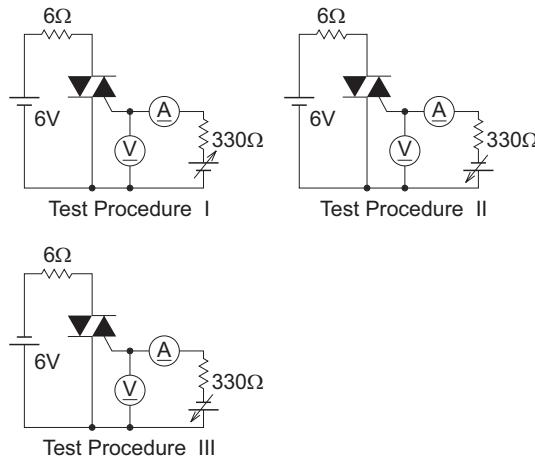




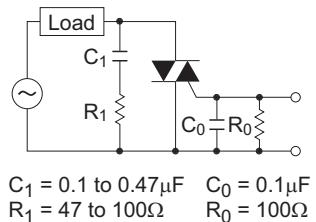
Gate Trigger Current vs.
Gate Current Pulse Width



Gate Trigger Characteristics Test Circuits



Recommended Circuit Values Around The Triac



$C_1 = 0.1 \text{ to } 0.47 \mu\text{F}$ $C_0 = 0.1 \mu\text{F}$
 $R_1 = 47 \text{ to } 100 \Omega$ $R_0 = 100 \Omega$

BCR25FM-12LB**Package Dimensions**

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	Unit: mm
TO-220FP	—	PRSS0003AG-A	—	1.9g	

The drawing provides detailed dimensions for the package. Key dimensions include:
- Top View: Lead spacing = 10.16 ± 0.20 mm, Lead thickness = 0.80 ± 0.20 mm, Lead height = 12.98 ± 0.30 mm.
- Side View: Total height = 15.87 ± 0.20 mm, Lead width = 5.08 ± 0.20 mm, Lead thickness = $0.50^{+0.10}_{-0.05}$ mm.

Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR25FM-12LB#BB0	Tube	50 pcs.	Straight type
BCR25FM-12LB□□#BB0	Tube	50 pcs.	□□:Lead forming type

Note : Please confirm the specification about the shipping in detail.